

October 2000 Revised October 2000

# 74LCXZ245

# **Low Voltage Bidirectional Transceiver** with 5V Tolerant Inputs and Outputs

## **General Description**

The 74LCXZ245 contains eight non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus oriented applications. The device is designed for low voltage (2.5V and 3.3V)  $V_{CC}$  applications with capability of interfacing to a 5V signal environment. The  $T/\overline{R}$  input determines the direction of data flow through the device. The  $\overline{OE}$  input disables both the A and B ports by placing them in a high impedance state.

The 74LCXZ245 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation. When  $\rm V_{CC}$  is between 0V and 1.5V, the 74LCXZ245 is on the high impedance state during power up or power down. This places the outputs in the high impedance (Z) state preventing intermittent low impedance loading or glitching in bus oriented applications.

### **Features**

- 5V tolerant inputs and outputs
- 2.3V-3.6V V<sub>CC</sub> specifications provided
- 7.0 ns  $t_{PD}$  max ( $V_{CC} = 3.3V$ ), 10  $\mu$ A  $I_{CC}$  max
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- $\pm$ 24 mA output drive ( $V_{CC} = 3.0V$ )
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:

Human body model > 2000V

Machine model > 200V

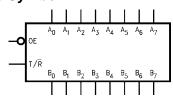
Note 1: To ensure the high-impedance state during power up or down,  $\overline{\text{OE}}$  should be tied to  $V_{CC}$  through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

# **Ordering Code:**

Order Number	Package Number	Package Description			
74LCXZ245WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide			
74LCXZ245SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide			
74LCXZ245MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide			
74LCXZ245MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide			

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

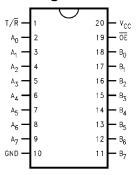
### **Logic Symbol**



### **Pin Descriptions**

Pin Names	Description
ŌĒ	Output Enable Input
T/R	Transmit/Receive Input
A <sub>0</sub> -A <sub>7</sub>	Side A Inputs or 3-STATE Outputs
B <sub>0</sub> -B <sub>7</sub>	Side B Inputs or 3-STATE Outputs

## **Connection Diagram**



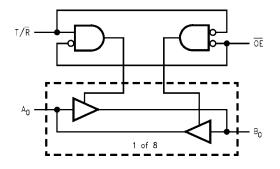
# **Truth Table**

Inp	outs	2.1.1.
OE	T/R	Outputs
L	L	Bus B <sub>0</sub> – B <sub>7</sub> Data to Bus A <sub>0</sub> – A <sub>7</sub>
L	Н	Bus A <sub>0</sub> – A <sub>7</sub> Data to Bus B <sub>0</sub> – B <sub>7</sub>
Н	Х	HIGH Z State on A <sub>0</sub> – A <sub>7</sub> , B <sub>0</sub> – B <sub>7</sub> (Note 2)

- H = HIGH Voltage Level L = LOW Voltage Level X = Immaterial Z = High Impedance

Note 2: Unused bus terminals during HIGH Z State must be held HIGH or LOW.

# **Logic Diagram**



#### **Absolute Maximum Ratings**(Note 3) Symbol Parameter Value Conditions Units ٧ Supply Voltage -0.5 to +7.0 $V_{CC}$ -0.5 to +7.0 ٧ DC Input Voltage $V_{I}$ DC Output Voltage Output in 3-STATE Vo -0.5 to +7.0 ٧ -0.5 to $V_{CC} + 0.5$ Output in HIGH or LOW State (Note 4) DC Input Diode Current -50 V<sub>I</sub> < GND mΑ $I_{\mathsf{IK}}$ DC Output Diode Current -50 V<sub>O</sub> < GND $I_{OK}$ mΑ +50 $V_O > V_{CC}$ DC Output Source/Sink Current ±50 mΑ lο $I_{CC}$ DC Supply Current per Supply Pin ±100 mΑ DC Ground Current per Ground Pin ±100 mΑ $I_{GND}$ Storage Temperature -65 to +150 °C $\mathsf{T}_{\mathsf{STG}}$

# Recommended Operating Conditions (Note 5)

Symbol	Parameter			Max	Units
V <sub>CC</sub>	Supply Voltage	Operating	2.7	3.6	V
V <sub>I</sub>	Input Voltage		0	5.5	V
Vo	Output Voltage	HIGH or LOW State	0	V <sub>CC</sub>	V
		3-STATE	0	5.5	V
I <sub>OH</sub> /I <sub>OL</sub>	Output Current	$V_{CC} = 3.0V - 3.6V$		±24	
		$V_{CC} = 2.7V - 3.0V$		±12	mA
		$V_{CC} = 2.3V - 2.7V$		±8	
T <sub>A</sub>	Free-Air Operating Temperature		-40	85	°C
Δt/ΔV	Input Edge Rate, $V_{IN} = 0.8V - 2.0V$ , $V_{CC} = 3.0V$		0	10	ns/V

Note 3: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 4:  $I_{\rm O}$  Absolute Maximum Rating must be observed.

Note 5: Unused inputs or I/O pins must be held HIGH or LOW. They may not float.

## **DC Electrical Characteristics**

Symbol	Parameter	Conditions	V <sub>CC</sub>	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units
Syllibol	Farameter	Conditions	(V)	Min	Max	Onics
V <sub>IH</sub>	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		v
V <sub>IL</sub>	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 - 3.6		0.8	
V <sub>OH</sub>	HIGH Level Output Voltage	$I_{OH} = -100  \mu A$	2.3 - 3.6	V <sub>CC</sub> - 0.2		
		$I_{OH} = -8 \text{ mA}$	2.3	1.8		
		$I_{OH} = -12 \text{ mA}$	2.7	2.2		V
		$I_{OH} = -18 \text{ mA}$	3.0	2.4		
		$I_{OH} = -24 \text{ mA}$	3.0	2.2		
V <sub>OL</sub>	LOW Level Output Voltage	$I_{OL} = 100 \mu A$	2.3 – 3.6		0.2	
		I <sub>OL</sub> = 8mA	2.3		0.6	
		I <sub>OL</sub> = 12 mA	2.7		0.4	V
		I <sub>OL</sub> = 16 mA	3.0		0.4	
		I <sub>OL</sub> = 24 mA	3.0		0.55	
l <sub>l</sub>	Input Leakage Current	0 ≤ V <sub>I</sub> ≤ 5.5V	2.3 – 3.6		±5.0	μΑ
l <sub>OZ</sub>	3-STATE I/O Leakage	$0 \le V_O \le 5.5V$	2.3 – 3.6		±5.0	μА
		$V_I = V_{IH}$ or $V_{IL}$	2.5 – 5.0		±3.0	μΛ
I <sub>OFF</sub>	Power-Off Leakage Current	$V_I$ or $V_O = 5.5V$	0		10	μΑ
I <sub>PU/PD</sub>	Power Up/ Power Down	$V_O = \text{to } V_{CC}$	0 – 1.5		±5.0	^
	3-STATE Output Current	$V_I = V_{CC}$ or GND	0 - 1.5		±3.0	μΑ

# DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V <sub>CC</sub>	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units
Cymbol	i didilicici		(V)	Min	Max	1 0
Icc	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		225	μА
		3.6V ≤ V <sub>I</sub> , V <sub>O</sub> ≤ 5.5V (Note 6)	2.3 – 3.6		±225	μΛ
$\Delta I_{CC}$	Increase in I <sub>CC</sub> per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 – 3.6		500	μΑ

Note 6: Outputs disabled or 3-STATE only.

# **AC Electrical Characteristics**

		$T_A = -40^{\circ}C$ to $+85^{\circ}C$ , $R_L = 500\Omega$				
Symbol	Parameter	$V_{CC} = 3.3V \pm 0.3V$ $C_L = 50 \text{ pF}$		V <sub>CC</sub> = 2.7V C <sub>L</sub> = 50 pF		Units
Syllibol	Farameter					
		Min	Max	Min	Max	
t <sub>PHL</sub>	Propagation Delay	1.5	7.0	1.5	8.0	20
t <sub>PLH</sub>	$A_n$ to $B_n$ or $B_n$ to $A_n$	1.5	7.0	1.5	8.0	ns
t <sub>PZL</sub>	Output Enable Time	1.5	8.5	1.5	9.5	ns
t <sub>PZH</sub>		1.5	8.5	1.5	9.5	115
t <sub>PLZ</sub>	Output Disable Time	1.5	7.5	1.5	8.5	ns
t <sub>PHZ</sub>		1.5	7.5	1.5	8.5	113
toshl	Output to Output Skew		1.0			ns
t <sub>OSLH</sub>	(Note 7)		1.0			113

Note 7: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (toSHL) or LOW-to-HIGH (toSLH).

# **Dynamic Switching Characteristics**

Symbol	Parameter	Conditions	V <sub>CC</sub>	T <sub>A</sub> = 25°C	Units
Symbol	Faranietei	Conditions	(V)	Typical	Oilles
V <sub>OLP</sub>	Quiet Output Dynamic Peak V <sub>OL</sub>	$C_L = 50 \text{ pF}, V_{IH} = 3.3V, V_{IL} = 0V$	3.3	0.8	
		$C_L = 30 \text{ pF}, V_{IH} = 2.5 \text{V}, V_{IL} = 0 \text{V}$	2.5	0.6	V
V <sub>OLV</sub>	Quiet Output Dynamic Valley V <sub>OL</sub>	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	-0.8	
		$C_L = 30 \text{ pF}, V_{IH} = 2.5 \text{V}, V_{IL} = 0 \text{V}$	2.5	-0.6	V

# Capacitance

Symbol	Parameter	Conditions	Typical	Units
C <sub>IN</sub>	Input Capacitance	$V_{CC} = Open, V_I = 0V \text{ or } V_{CC}$	7	pF
C <sub>I/O</sub>	Input/Output Capacitance	$V_{CC} = 3.3V$ , $V_I = 0V$ or $V_{CC}$	8	pF
C <sub>PD</sub>	Power Dissipation Capacitance	$V_{CC} = 3.3V$ , $V_{I} = 0V$ or $V_{CC}$ , $f = 10$ MHz	25	pF

# AC LOADING and WAVEFORMS Generic for LCX Family

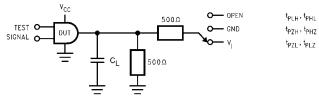
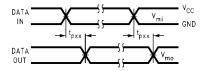
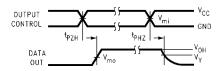


FIGURE 1. AC Test Circuit ( $C_L$  includes probe and jig capacitance)

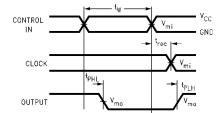
Test	Switch
t <sub>PLH</sub> , t <sub>PHL</sub>	Open
t <sub>PZL</sub> , t <sub>PLZ</sub>	6V at $V_{CC} = 3.3 \pm 0.3V$ $V_{CC}$ x 2 at $V_{CC} = 2.5 \pm 0.2V$
$t_{PZH}, t_{PHZ}$	GND



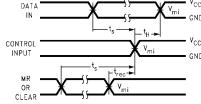
Waveform for Inverting and Non-Inverting Functions



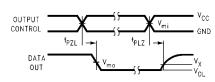
3-STATE Output High Enable and Disable Times for Logic



Propagation Delay. Pulse Width and t<sub>rec</sub> Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

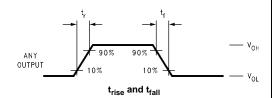
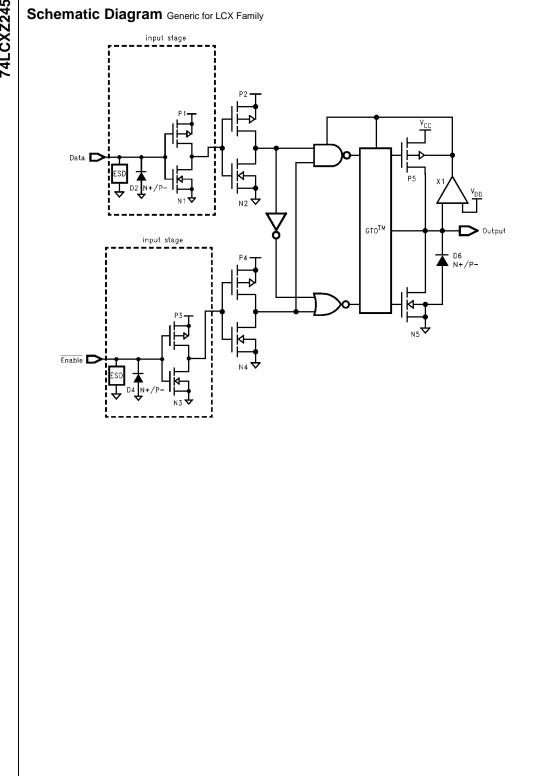
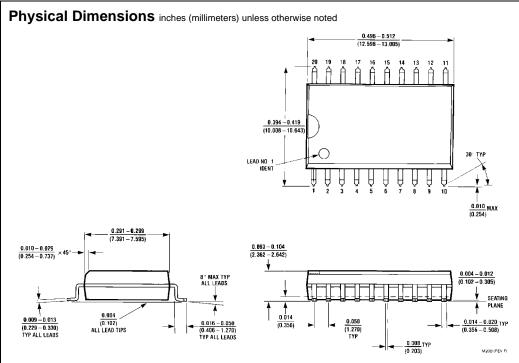


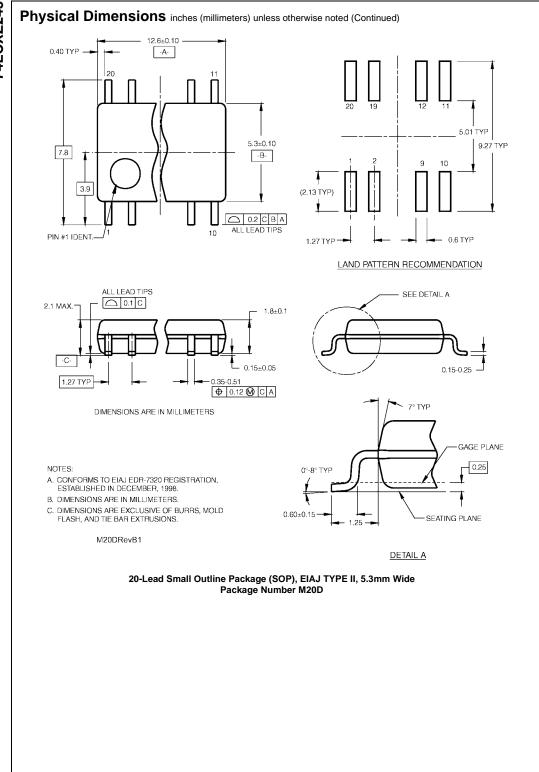
FIGURE 2. Waveforms (Input Characteristics; f =1MHz,  $t_R = t_F = 3ns$ )

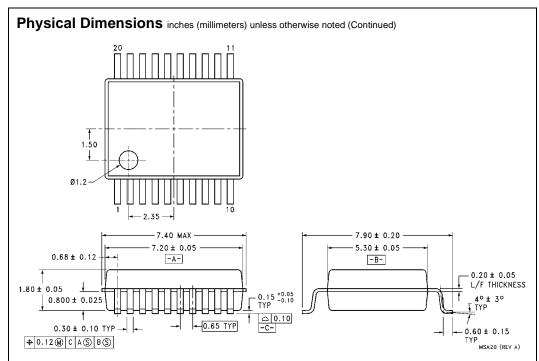
Symbol	V <sub>CC</sub>				
Cymbol	$\textbf{3.3V} \pm \textbf{0.3V}$	2.7V	2.5V ± 0.2V		
V <sub>mi</sub>	1.5V	1.5V	V <sub>CC</sub> /2		
$V_{mo}$	1.5V	1.5V	V <sub>CC</sub> /2		
V <sub>x</sub>	V <sub>OL</sub> + 0.3V	V <sub>OL</sub> + 0.3V	V <sub>OL</sub> + 0.15V		
V.,	V <sub>OH</sub> – 0.3V	V <sub>OH</sub> - 0.3V	V <sub>OH</sub> – 0.15V		



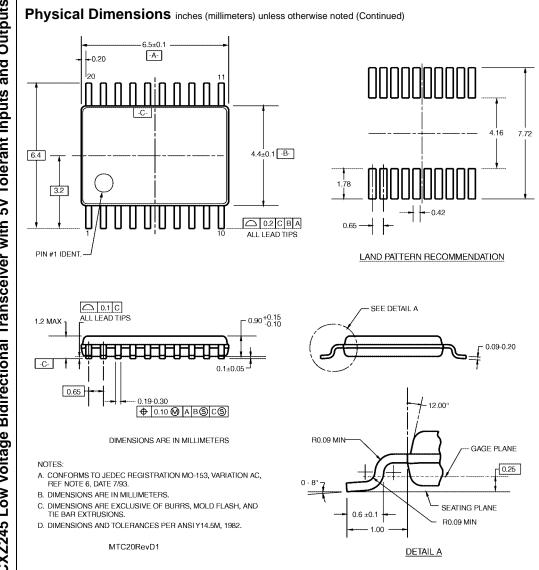


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Package Number M20B





20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide Package Number MSA20



20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide Package Number MTC20

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